Computer-Aided VLSI System Design

Final Project: Gauss-Seidel Iteration Machine

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Introduction

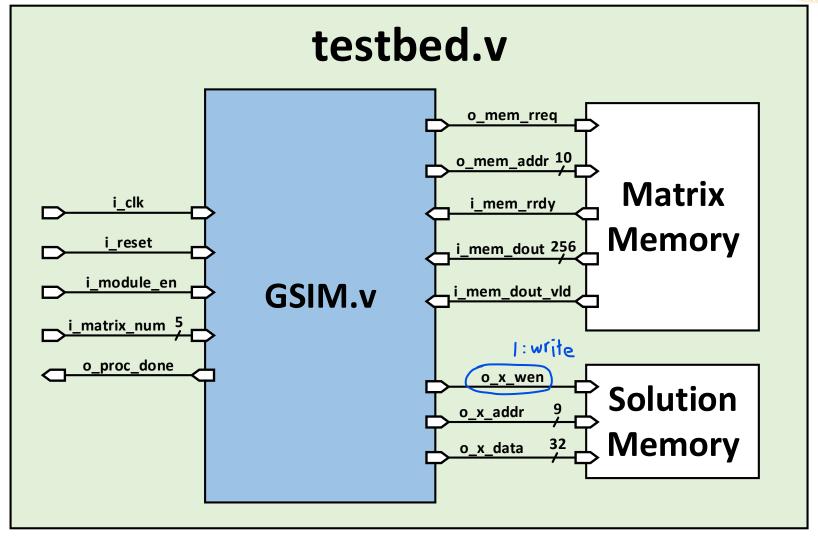


- 請完成一Gauss-Seidel Iteration Machine(GSIM)的電路設計來求出 多元線性聯立方程式(Linear Equation)之解
- 如下圖所示,矩陣A、B為已知之整數值,待求矩陣X之解
 - 在此專題中·N固定為16

$$\mathsf{AX=B} \longrightarrow \begin{bmatrix} a_{11} & a_{12} & \dots & a_{1N} \\ a_{21} & a_{22} & \dots & a_{2N} \\ \dots & \dots & \dots & \dots \\ a_{N1} & a_{N2} & \dots & a_{NN} \end{bmatrix} \begin{bmatrix} x_1 \\ x_2 \\ \dots \\ x_N \end{bmatrix} = \begin{bmatrix} b_1 \\ b_2 \\ \dots \\ b_N \end{bmatrix}$$

Block Diagram





Input/Output

Signal Name	I/O	Width	Simple Description
i_clk	I	1	本系統為同步於時脈正緣之同步設計。 (註: Host端採clk正緣時送資料。)
i_reset	I	1	高位準"非"同步(active high asynchronous)之系統重置信號。
i_module_en	I	1	模組控制訊號。當為high時模組操作有效。
i_matrix_num	I	5	要計算矩陣數量。
o_proc_done	0	1	運算完成訊號。當將所有要求的解輸出後,須將此訊號設為high代表運算完成,並在i_module_en為0時再設為low。
o_mem_rreq	0	1	要讀取matrix memory時須設為high。
o_mem_addr	0	10	要讀取matrix memory之位址。
i_mem_rrdy	I	1	要讀取matrix memory之ready訊號。為high時代表此時可讀取 memory data。
i_mem_dout	I	256	Matrix memory data。共有16 筆16-bit 資料,採用2's complement表示。細節請參考。
i_mem_dout_vld	I	1	Matrix memory data有效訊號。為high時代表此時i_mem_dout有效。
o_x_wen	0	1	輸出資料有效之控制訊號。當為High時,表示目前輸出的資料為有效的。
o_x_addr	0	9	輸出矩陣解之位址。
o_x_data	0	32	要輸出之矩陣解。採用2's complement表示(16-bit整數+16-bit小數)。

Gauss-Seidel Iteration Machine



■ 所求多元線性聯立方程式如下式所示

$$a_{11}x_{1} + a_{12}x_{2} + \dots + a_{1N}x_{N} = b_{1}$$

$$a_{21}x_{1} + a_{22}x_{2} + \dots + a_{2N}x_{N} = b_{2}$$

$$\vdots$$

$$a_{N1}x_{1} + a_{N2}x_{2} + \dots + a_{NN}x_{N} = b_{N}$$
(1)

■ 欲求 $x_1, x_2, ..., x_N$ 的值,可以將上式整理成底下式子

$$x_{1}^{1} = \frac{1}{a_{11}} (b_{1} - a_{12}x_{2}^{0} - \dots - a_{1N}x_{N}^{0})$$

$$x_{2}^{1} = \frac{1}{a_{22}} (b_{2} - a_{21}x_{1}^{1} - a_{23}x_{3}^{0} - \dots - a_{2N}x_{N}^{0})$$

$$\vdots$$

$$x_{N}^{1} = \frac{1}{a_{NN}} (b_{N} - a_{N1}x_{1}^{1} - a_{N2}x_{2}^{1} - \dots - a_{NN-1}x_{N-1}^{1})$$
(2)

Gauss-Seidel Iteration Machine

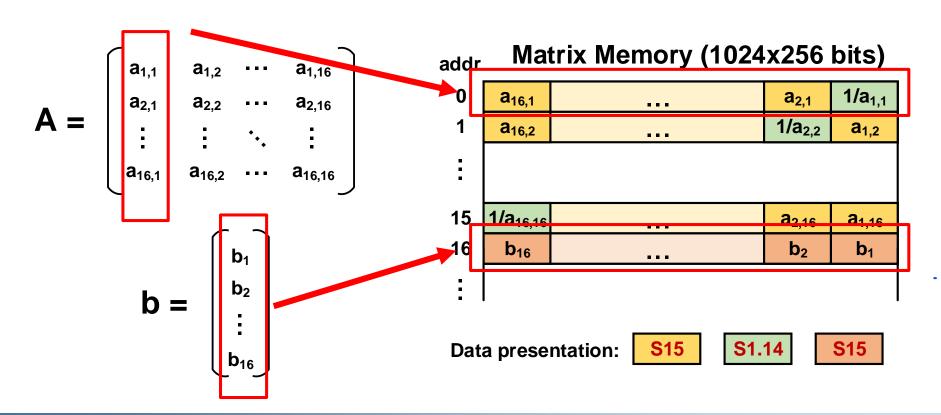
- Gauss-Seidel Iteration就是將(2)式作相同的動作數次的疊代,其行為如下式所示,反覆地疊代數次後,即可將所有待求的x值收斂在某一個值,該x值即為所求,
 - 在此專題中,疊代次數固定為16。

$$x_i^{k+1} = \frac{1}{a_{ii}} \left[b_i - \sum_{j=1}^{i-1} a_{ij} x_j^{k+1} - \sum_{j=i+1}^{N} a_{ij} x_j^k \right]$$
 (3)

Data Presentation



- 2's complement
 - Ex. 16-bit(2-bit整數+14-bit小數) -> \$1.14
- 矩陣A及b都是放在外面的memory中,由設計者決定怎麼讀取



Order for Computation

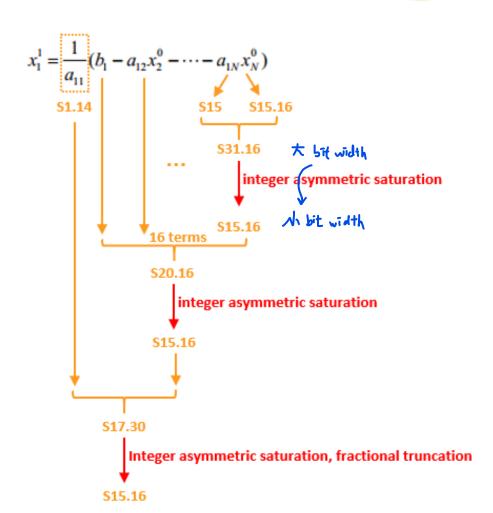


Integer asymmetric saturation

若發生overflow,則取其能表示的最大值/最小值來做為結果

Fractional truncation

小數部分當bit-width變小時 直接truncate即可(不用四捨 五入)



Initialization



■ X初始化方式如下

$$X^{0} = \begin{bmatrix} x_{1}^{0} \\ x_{2}^{0} \\ \vdots \\ x_{N}^{0} \end{bmatrix} = \begin{bmatrix} b_{I}/a_{II} \\ b_{2}/a_{22} \\ \dots \\ b_{N}/a_{NN} \end{bmatrix}$$
S15.16 S17.14

b_N: S15

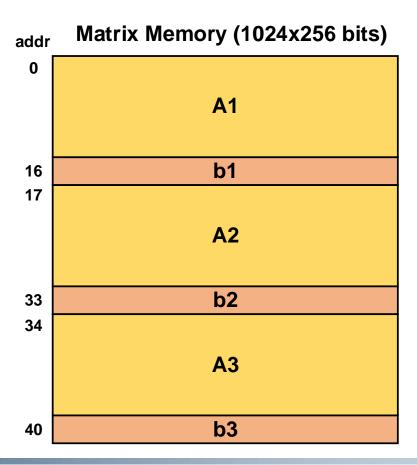
1/a_{NN}: \$1.14

Integer asymmetric saturation

Matrix Storage

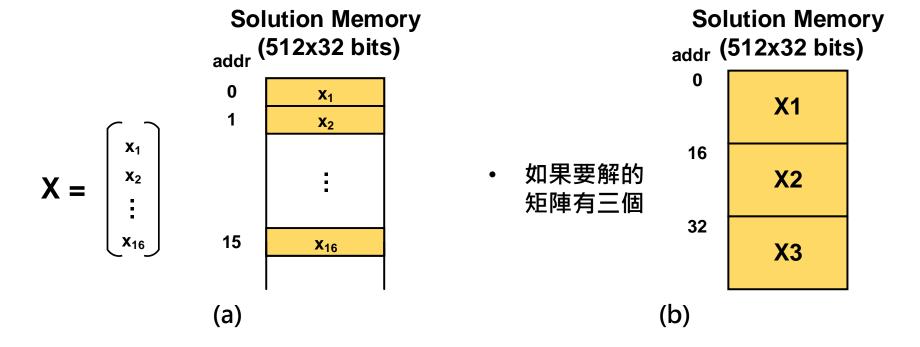


■ 假設要處理3個矩陣·則其儲存在memory的順序如下



Result Output

- 將矩陣解輸出儲存至solution memory
 - 一次只輸出32-bit答案



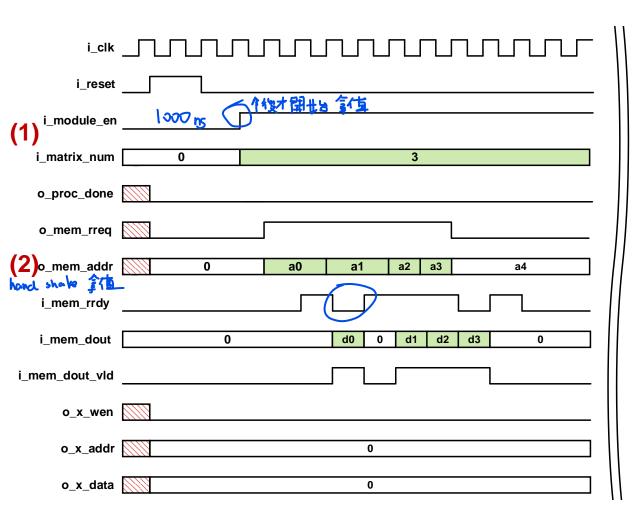
Specification

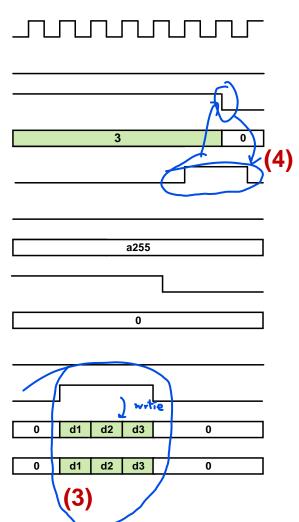


- Only worst-case library is used for synthesis.
- The slack for setup-time should be non-negative.
- No any timing violation and glitches for the gate level simulation and post-layout simulation.

Waveform

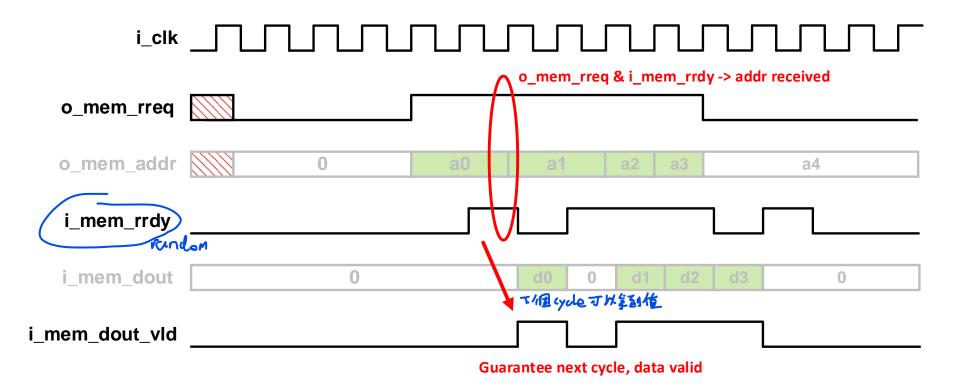






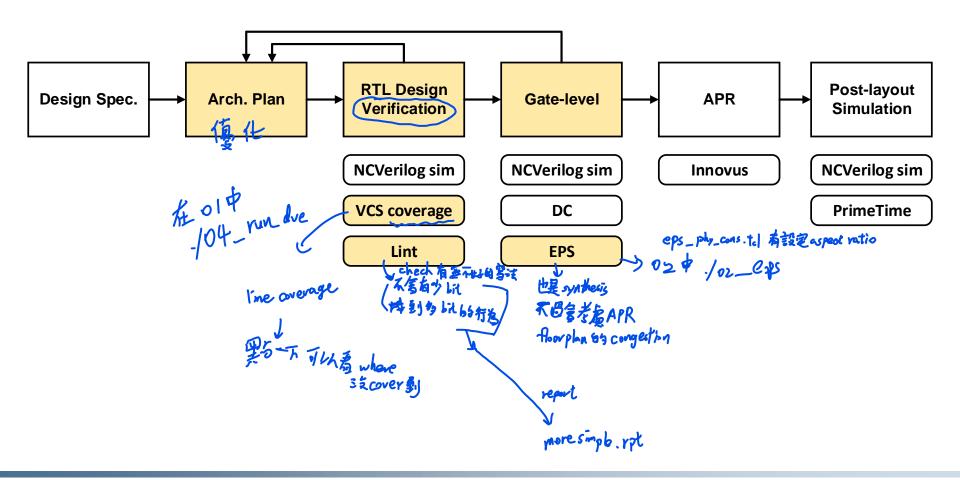
Handshake





Design Flow

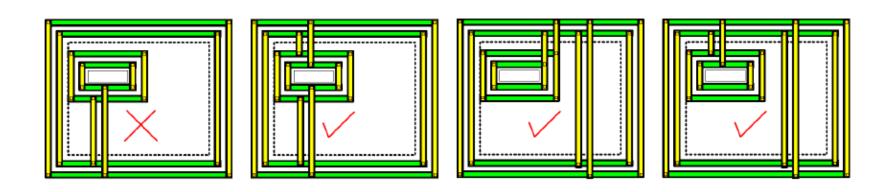




Specifications for APR (1)

- 只需做 Marco layout 即不用包含 IO Pad 、 Bonding Pad)

 ②是零セ☆ 飲料
- set_aspect_ratio 0.6
- VDD 與 VSS Power Ring 寬度請各設定為 2um 只須做一組
- 不需加 Dummy Metal
- Power Stripe 務必至少加一組 , 其 VDD 、 VSS 寬度各設定為 2um
 - Power Stripe 垂直方向至少一組,水平方向可不加



分散PIN

Specifications for APR (2)



- 務必要加 Power RaiD(follow pin)
- Core Filler 務必要加
- APR 後之 GDSII) 檔案務必產生
- 完成 APR DRC/LVS 完全無誤
- 記得先產生GSIM.ioc,再重新讀取該檔來設定(pin position)

Grading Policy (1)



Baseline 50% + Performance 35% + Report 15%

Item		%	Description	
RTL Simulation		10	通過提供的pattern (hand shalee)	
Verification		10	Coverage (line 100%), nLint no Error	
Synthesis		15	EPS, Pass gate-level sim & LEC	
APR		15	Finish APR with no DRC/LVS errors Pass post-layout simulation	
Performance	Area, time	20	Area x Time	
	Power	15	10:Compare active window, total energy 5: idle, idle_after_active	
Report		15		

Performance



- Score = Area x Time
 - Area

innovus #> analyzeFloorplan

Time

```
tb0 ~ tb3
```

```
----- Congratulation! You have pass all the pattern! -----
Simulation complete via $finish(1) at time 404572700 PS + 0
../00_TESTBED/testbench.v:171 $finish;
```

Grading Policy (2)



Baseline 50% + Performance 40% + Report 10%

Violation	Penalty
不符合 design specification	Performance*0.5
無法通過hidden pattern	Performance*0.5
沒有考慮random i_mem_rrdy	Performance不評分
違反繳交格式與規則	總分-3

Report



- 需要包含底下幾個項目
 - 架構設計
 - 硬體優化方法 (latency, area, power...) なんが 地え いかまんな ひょう
 - nLint report with 0 errors
 - Coverage result
 - Congestion map (如果有跑EPS流程)
 - Primetime power report (Post-layout)
 - Layout
 - Area result
 - Performance 表格

Submission (1)



- GSIM.v
- GSIM_syn.v
- GSIM_syn.sdf
- GSIM_pr.v
- GSIM_pr.sdf
- GSIM.gds
- active.power
- idle.power
- idle_after_active.power
- GSIM_final.tar (archive of the design database directory)
- report pdf
- all other design files included in your design for rtl simulation (optional)



Submission (2)



- Due Wednesday, Jan. 14, 23:59
- Final project presentation (MTK experience sharing)
 - Date: January 18, 2021